

400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

FEATURES AND BENEFITS

- High operating bandwidth for fast control loops or where high-speed currents are monitored
 400 kHz bandwidth
 - □ 1.1 µs typical response time
- High accuracy
 - □ 1% maximum sensitivity error over temperature (K series)
 - □ 8 mV maximum offset voltage over temperature
 - \Box Non-ratiometric operation with V_{REF} output
 - □ Low noise LA package
 - \diamond 160 mV_{RMS} for 3.3 V supply
 - \diamond 124 mV_{RMS} for 5 V supply
 - Differential sensing for high immunity to external magnetic fields
 - \square No magnetic hysteresis
- Adjustable fast overcurrent fault
 - \Box 1 µs typical response time
 - $\hfill\square$ Pin adjustable threshold
- Externally configurable gain settings using two logic pins
 Four adjustable gain levels for increased design flexibility

Continued on the next page

PACKAGE: 16-Pin SOICW (suffix MA/LA)



Not to scale

DESCRIPTION

The ACS37002 is a fully integrated Hall-effect current sensor in an SOICW-16 package that is factory-trimmed to provide high accuracy over the entire operating range without the need for customer programming. The current is sensed differentially by two Hall plates that subtract out interfering external commonmode magnetic fields.

The package construction provides high isolation by magnetically coupling the field generated by the current in the conductor to the monolithic Hall sensor IC which has no physical connection to the integrated current conductor. The MA package is optimized for higher isolation with dielectric withstand voltage, 3125 V_{RMS}, and 0.85 m Ω conductor resistance. The LA package is optimized for lower noise with 2250 V_{RMS} dielectric withstand voltage and 1 m Ω conductor resistance.

The ACS37002 has functional features that are externally configurable and robust without the need for programming. Two logic gain selection pins can be used to configure the device to one of four defined sensitivities and corresponding current ranges. A fast overcurrent fault output provides shortcircuit detection for system protection with a fault threshold that is proportional to the current range and can be set with an analog input. The reference pin provides a stable voltage that corresponds to the 0 A output voltage. This reference voltage allows for differential measurements as well as a device-referred voltage to set the overcurrent fault threshold.

Devices are RoHS compliant and lead (Pb) free with 100% matte-tin-platted leadframes.

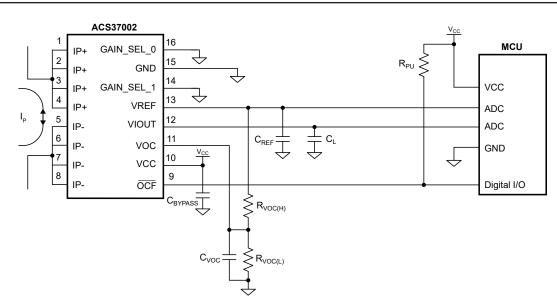


Figure 1: Typical Bidirectional Application Showing 00 Gain Select Configuration. For more application circuits, refer to the Application and Theory section.

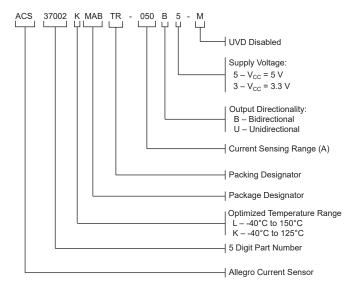
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FEATURES AND BENEFITS (continued)

- □ Enabling measurement ranges from 10 to 133 A in both unidirectional and bidirectional modes
- Low internal primary conductor resistance 0.85 m Ω (MA) and 1 m Ω (LA) for better power efficiency
- UL 62368-1:2014 (ed. 2) certification, highly isolated compact SOICW-16 surface mount package (MA)
 □ 3125 V_{RMS} rated dielectric withstand voltage
 □ 1097 V_{RMS} / 1550 V_{DC} basic insulation voltages
 - \Box 565 V_{RMS} / 800 V_{DC} reinforced insulation voltages
- Wide operating temperature, -40°C to 150°C
- AEC-Q100 Grade 0, automotive qualified





SELECTION GUIDE

Part Number	Current Sensing Range, I _{PR} (A)	Sensitivity ^[1] (mV/A)	Nominal V _{CC} (V)	Optimized Temp. Range T _A (°C)	Packing ^[2]
	MA	Package, 16-Pin SOICW			~
ACS37002LMABTR-050B5-M	±33, ±40, ±50, ±66	60, 50, 40, 30			
ACS37002LMABTR-066B5-M	±66, ±80 ±100, ±133	30, 25, 20, 15			
ACS37002LMABTR-050U5-M	33, 40, 50, 66	120, 100, 80, 60	- 5		
ACS37002LMABTR-066U5-M	66, 80, 100, 133	60, 50, 40, 30			
ACS37002LMABTR-050B3	±33, ±40, ±50, ±66	39.6, 33, 26.4, 19.8		40 to 150	1000 pieces
ACS37002LMABTR-066B3	±66, ±80, ±100, ±133	19.8, 16.5, 13.2, 9.9			per 13-inch reel
ACS37002LMABTR-050U3	33, 40, 50, 66	79.2, 66, 52.8, 39.6	- 3.3		
ACS37002LMABTR-066U3	66, 80, 100, 133	39.6, 33, 26.4, 19.8			
ACS37002KMABTR-050B5-M	±33, ±40, ±50, ±66	60, 50, 40, 30	5	40 to 405 [2]	
ACS37002KMABTR-050B3	±33, ±40, ±50, ±66	39.6, 33, 26.4, 19.8	3.3	40 to 125 ^[3]	
	LA	Package, 16-Pin SOICW			·
ACS37002LLAATR-015B5	±10, ±12, ±15, ±20	200,166.6,133.3,100			
ACS37002LLAATR-025B5	±25, ±30, ±37.5, ±50	80, 66.6, 53.3, 40	- 5	10 to 150	1000 pieces
ACS37002LLAATR-015B3	±10, ±12, ±15, ±20	132, 110, 88, 66	2.2	-40 to 150	per 13-inch reel
ACS37002LLAATR-025U3	25, 30, 37.5, 50	105.6, 88, 70.4, 52.8	- 3.3		

^[1] Refer to the part specific performance characteristics sections for Gain_Sel configuration.

^[2] Contact Allegro for additional options.

[3] The device performance is optimized from -40°C to 125°C; however, the device can still operate to an ambient temperature of 150°C. The device shares the same qualifications as the L temperature devices unless otherwise stated.



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Table of Contents

Features and Benefits	1
Description	1
Packages	1
Selection Guide	2
Absolute Maximum Ratings	4
Isolation and Package Characteristics	5
MA Package Specific Performance	5
LA Package Specific Performance	5
Pinout Diagram and Terminal List	6
Functional Block Diagram	7
Common Electrical Characteristics	8
Performance Characteristics	11
Functional Description	25
Power-On Reset Operation	
Power-On/Power-Off	25
Overvoltage Detection (OVD)	26
Absolute Maximum Ratings	27
Supply Zener Clamp Voltages	
Forward and Reverse Supply Voltage	
Forward and Reverse Output Voltage	
Forward and Reverse Reference/Fault Voltage	
Output Source and Sink Current	
Definitions of Operating and Performance Characteristics	
Zero Current Voltage Output (V _{IOUT(Q)} , QVO)	
QVO Temperature Drift (V _{QE})	28
Reference Voltage (V _{REF})	28
Reference Voltage Temperature Drift (VRE)	28
Offset Voltage (VOE)	28
Output Saturation Voltage (V _{SAT(HIGH/LOW)})	28
Output Voltage Operating Range (V _{OOR})	28
Sensitivity (Sens)	
Sensitivity Error (E _{sens})	
Gain Selection Pins	
Full Scale (FS)	
Nonlinearity (É _{LIN})	
Total Output Error (E _{TOT})	

Power Supply Offset Error (V _{PS})	. 30
Offset Power Supply Rejection Ratio (PSRRO)	. 30
Power Supply Sensitivity Error (EPS)	. 30
Sensitivity Power Supply Rejection Ratio (PSRRS)	. 30
Fault Behavior	. 31
Overcurrent Fault (OCF)	. 31
Overcurrent Fault Operating Range/Point (I _{OCF-OR} , I _{OCF-OP})	31
Overcurrent Fault Hysteresis (I _{OCF-Hyst})	
Voltage Overcurrent Pin (VOC)	
Overcurrent Fault Error (E _{OCF})	
Overcurrent Fault Response Time (t _{OCF})	
Overcurrent Fault Reaction Time (t _{OCF-R})	
Overcurrent Fault Mask Time (t _{OCF-MASK})	
Overcurrent Fault Hold Time (t _{OCF-HOLD})	
Overcurrent Fault Persist	
OCF Disable	. 32
Response Characteristics Definitions and Performance Data	. 33
Response Time (t _{RESPONSE})	. 33
Propagation Time (t _{pd})	
Rise Time (t _R)	
Output Slew Rate (SR)	
Temperature Compensation	. 34
Temperature Compensation Update Rate	. 34
Application and Theory	
Application Circuits	
Theory and Functionality – VOC and OCF	. 36
VOC Driven by Non-Inverting Buffered VREF	. 36
Power Supply Decoupling Capacitor and	
Output Capacitive Loads	
Dynamically Change Gain in a System	
Thermal Performance	
Thermal Rise vs. Primary Current	
Evaluation Board Layout	
Package Outline Drawings	
MA Package	. 39
LA Package	. 40



ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	N	otes	Rating	Unit				
Forward Supply Voltage	V _{FCC}			6.5	V				
Reverse Supply Voltage	V _{RCC}			-0.5	V				
Forward Output Voltage	V _{FIOUT}	Applies to V _{IOUT} , V _{OCF} , ar	nd V _{REF}	$(V_{CC} + 0.7) \le 6.5$	V				
Reverse Output Voltage	V _{RIOUT}	Applies to V _{IOUT} , V _{OCF} , ar	nd V _{REF}	-0.5	V				
Forward Input Voltage	V _{FI}	Applies to GAIN_SEL0, G	SAIN_SEL1, and VOC	$(V_{CC} + 0.7) \le 6.5$	V				
Reverse Input Voltage	V _{RI}	Applies to GAIN_SEL0, G	SAIN_SEL1, and VOC	-0.5	V				
Maximum Continuous Current ^[1]		T _A = 25°C MA package LA package	MA package	60	А				
	ICMAX		LA package	MAX IA-23 C LA package	LA package	LA package	LA package	LA package	55
Operating Ambient Temperature	T _A				°C				
Storage Temperature	T _{stg}			-65 to 165	°C				
Maximum Junction Temperature	T _{J(max)}			165	°C				

^[1] Tested on the ASEK37002 Evaluation Board (TED-0002825).



ISOLATION AND PACKAGE CHARACTERISTICS

Characteristic	Symbol	Notes	Rating	Unit
Dielectric Surge Voltage	V _{SURGE}	Tested in oil, ± 5 pulses at 2/minute in compliance to IEC 61000-4-5 1.2 µs (rise) / 50 µs (width)	10	kV
Surge Current ^[1]	I _{SURGE}	Tested in compliance to IEC 61000-4-5 8 μs (rise) / 20 μs (width)		kA
Comparative Track Index	CTI	Material Group II	400 to 599	V
Moisture Sensitivity Level	MSL	Per IPC/JEDEC J-STD-020	3	_

^[1] Certification pending.

MA PACKAGE SPECIFIC PERFORMANCE

Characteristic	Symbol	Notes	Rating	Unit
Distance Through Insulation	DTI	Minimum internal distance through insulation		μm
Dielectric Withstand Voltage	V _{ISO}	Agency rated for 60 seconds per UL 62368-1:2014 (edition 2) [1][2]	3125	V _{RMS}
Impulse Withstand Voltage	VIMPULSE	Tested in air, ± 5 pulses at 2/minute in compliance to IEC 61000-4-5 1.2 μ s (rise) / 50 μ s (width)		V _{PK}
Working Voltage for Basic Insulation	V	Maximum approved working voltage for basic insulation according	1550	V _{PK or} V _{DC}
Working Voltage for Basic Insulation	V _{WVBI}	to UL 62368-1:2014 (edition 2)	1097	V _{RMS}
Working Voltage for Reinforced	V	RI Maximum approved working voltage for reinforced insulation according to UL 62368-1:2014 (edition 2)		V _{PK or} V _{DC}
Insulation	V _{WVRI}			V _{RMS}
Clearance	D _{cl}	Minimum distance through air from IP leads to signal leads		mm
Creepage	D _{cr}	Minimum distance along package body from IP leads to signal leads	7.9	mm

 $^{[1]}$ Production tested for 1 second at 3125 V_{RMS} per UL 62368-1 (edition 2). $^{[2]}$ Agency type-tested at 5000 V for 1 minute per UL 62368-1 (edition 2) Section 5.4.7.

LA PACKAGE SPECIFIC PERFORMANCE

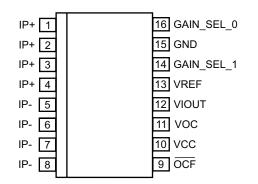
Characteristic	Symbol	Notes	Rating	Unit
Distance Through Insulation	DTI	Minimum internal distance through insulation		μm
Dielectric Withstand Voltage	V _{ISO}	Agency rated for 60 seconds per UL 62368-1:2014 (edition 2) ^{[1][2]}	2250	V _{RMS}
Impulse Withstand Voltage	VIMPULSE	Tested in air, ±5 pulses at 2/minute in compliance to IEC 61000-4-5 1.2 μs (rise) / 50 μs (width)	4000	V _{PK}
Working Voltage for Basic Insulation	V	Maximum approved working voltage for basic insulation according	870	V _{PK or} V _{DC}
[3]	V _{WVBI}	to UL 62368-1:2014 (edition 2)	616	V _{RMS}
Clearance ^[3]	D _{cl}	Minimum distance through air from IP leads to signal leads	7.5	mm
Creepage ^[3]	D _{cr}	Minimum distance along package body from IP leads to signal leads	7.5	mm

 $^{[1]}$ Production tested for 1 second at 2250 V_{RMS} per UL 62368-1 (edition 2). $^{[2]}$ Agency type-tested at 3600 V for 1 minute per UL 62368-1 (edition 2) Section 5.4.7.

^[3] Certification pending.



PINOUT DIAGRAM AND TERMINAL LIST TABLE





Terminal List Table

Number	Name	Description
1, 2, 3, 4	IP+	Terminals for current being sensed; fused internally
5, 6, 7, 8	IP-	Terminals for current being sensed; fused internally
9	OCF	Overcurrent fault, open-drain
10	VCC	Device power supply terminal
11	VOC	Overcurrent fault operation point input
12	VIOUT	Analog output representing the current flowing through I_P
13	VREF	Zero current voltage reference
14	GAIN_SEL_1	Gain selection bit 1
15	GND	Device ground terminal
16	GAIN_SEL_0	Gain selection bit 0



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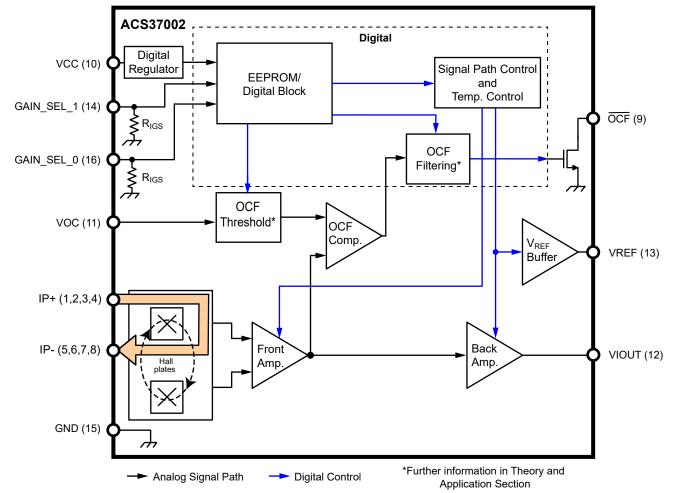


Figure 3: Functional Block Diagram



External Outputs

COMMON ELECTRICAL CHARACTERISTICS: Valid through full operating temperature range, $T_A = -40^{\circ}$ C to 150°C, $C_{BYPASS} = 0.1 \mu$ F, and $V_{CC} = 5 V$ or 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Cumples) (alterna	M	5 V devices only		5	5.5	V
Supply Voltage	V _{CC}	3.3 V devices only	3.15	3.3	3.6	V
Original and the Original Anti-		No load on VIOUT or VREF; V _{CC} = 5 V	_	13	18	mA
Supply Current	I _{CC}	No load on VIOUT or VREF; V_{CC} = 3.3 V	_	12	15	mA
Supply Bypass Capacitor	CBYPASS	VCC to GND recommended	0.1	_	-	μF
Output Resistive Load	RL	VIOUT to GND, VIOUT to VCC	10	_	_	kΩ
Output Capacitive Load	CL	VIOUT to GND	_	1	6	nF
Reference Resistive Load	R _{VREF}	VREF to GND (recommended to supply VOC); VREF to VCC	10	_	_	kΩ
Reference Capacitive Load	C _{VREF}	VREF to GND	_	_	6	nF
Fault Pull-Up Resistance	R _{PU}		4.7	_	500	kΩ
Drimon Conductor Desistance	R _{IP}	MA,T _A = 25°C	_	0.85	_	mΩ
Primary Conductor Resistance		$LA, T_A = 25^{\circ}C$	_	1	_	mΩ
Drimon Conductor Inductor	L _{IP}	MA package	_	4.2	-	nH
Primary Conductor Inductance		LA package	_	5	-	nH
Output Buffer Resistance	R _{OUT}	Internal output buffer resistance on VIOUT and VREF	_	4	-	Ω
	V _{POR(H)}	V _{CC} rising ^[1]		2.9	3.1	V
Power-On Reset Voltage	V _{POR(L)}	V _{CC} falling ^[1]	2.2	2.5	2.8	V
POR Hysteresis	V _{POR(HYS)}		250	_	-	mV
Power-On Time	t _{POD}	Time from V _{CC} rising ≥ V _{POR(H)} after a POR event until power-on; VREF, OCF, VIOUT	100	_	-	μs
Overvoltage Detection (OVD)	V _{OVD(H)}	$T_A = 25^{\circ}C, V_{CC} rising$ ^[1]	6.1	6.3	6.8	V
Threshold	V _{OVD(L)}	$T_A = 25^{\circ}C, V_{CC}$ falling ^[1]	5.6	5.8	6.1	V
Overvoltage Detection Hysteresis	V _{OVD(HYS)}		_	660	_	mV
	t _{dOVD(E)}	Time from V _{CC} rising ≥ V _{OVD(EN)} until OVD asserts	35	90	120	μs
OVD Delay Time	t _{dOVD(D)}	Time from V _{CC} falling ≤ V _{OVD(DIS)} until OVD clears	_	7	_	μs

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COMMON PERFORMANCE CHARACTERISTICS (VIOUT): Valid through full operating temperature range, $T_A = -40^{\circ}$ C to 150°C, $C_{BYPASS} = 0.1 \mu$ F, and $V_{CC} = 5 V$ or 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions		Min.	Тур.	Max.	Units
OUTPUT SIGNAL CHARACT	ERISTICS ((V _{IOUT})					
	V _{SAT(H)}	$R_L = 10 \text{ k}\Omega \text{ to GND}$		V _{CC} – 0.25	_	_	V
Saturation Voltage	V _{SAT(L)}	$R_L = 10 \text{ k}\Omega \text{ to } V_{CC}$		-	_	0.15	V
		5 V linear operating range		0.5	_	4.5	V
Output Operating Range	V _{OOR}	3.3 V linear operating range	.3 V linear operating range			3.0	V
	I _{OUT(src)}	/ _{IOUT} shorted to GND		_	25	_	mA
Output Current Limit	I _{OUT(snk)}	V _{IOUT} shorted to V _{CC}		_	25	_	mA
Output Drive	I _{OUT}			4.8	_	_	mA
Bandwidth	BW	Small signal –3 dB, C _L = 6 nF		_	400	_	kHz
Rise Time	t _R	$T_{A} = 25^{\circ}C, C_{L} = 6 \text{ nF}$		-	0.7	2.5	μs
Response Time	t _{RESPONSE}	$T_{A} = 25^{\circ}C, C_{L} = 6 \text{ nF}$		-	1.1	2.5	μs
Propagation Delay	t _{pd}	T _A = 25°C, C _L = 6 nF		-	0.7	2	μs
	I _{ND}	Input-referenced noise density;	MA Package	-	350	_	µA/√Hz
		$T_A = 25^{\circ}C, C_L = 6 \text{ nF}; V_{CC} = 5 \text{ V}$	LA Package	_	155	_	µA/√Hz
Noise Density		Input-referenced noise density; T _A = 25°C, C _L = 6 nF; V _{CC} = 3.3 V	MA Package	_	450	_	µA/√Hz
			LA Package	_	200	_	µA/√Hz
	I _N	Input-referenced noise at 400 kHz; $T_A = 25^{\circ}C$, $C_L = 6 nF$; $V_{CC} = 5 V$	MA Package	_	277	_	mA _{RMS}
			LA Package	_	124	_	mA _{RMS}
Noise		Input-referenced noise at 400 kHz; $T_A = 25^{\circ}C$, $C_L = 6 nF$; $V_{CC} = 3.3 V$	MA Package	-	357	_	mA _{RMS}
			LA Package	-	160	_	mA _{RMS}
Nonlinearity	E _{LIN}			_	±0.75	_	%
Power Supply Rejection Ratio		$T_A = 25^{\circ}C$, DC to 1 kHz, 100 mV pk-pk r V _{CC(typ)} , I _P = 0 A	ipple around V_{CC} =	-	-40	_	dB
Offset	PSRR _O	$T_A = 25^{\circ}C$, 1 to 100 kHz, 100 mV pk-pk r V _{CC(typ)} , I _P = 0 A	ipple around V _{CC} =	-	-30	_	dB
Power Supply Rejection Ratio	PSRRs	$T_A = 25^{\circ}C$, DC to 1 kHz, 100 mV pk-pk r V _{CC(typ)} , I _P = I _{PR(MAX)}	ipple around V _{CC} =	-	-15	_	dB
Sens	PSRRS	$T_A = 25^{\circ}C$, 1 to 100 kHz, 100 mV pk-pk ripple around $V_{CC} = V_{CC(typ)}$, $I_P = I_{PR(MAX)}$		-	6	_	dB
		Bidirectional; V _{CC} @ V _{CC(MIN)} or V _{CC(MA}	X)	-10	_	10	mV
Power Supply Offset Error	V _{OE(PS)}	Unidirectional; V _{CC} @ V _{CC(MIN)} or	MA Package	-18	_	18	mV
		V _{CC(MAX)}	LA Package	-10	_	10	mV
Power Supply Sensitivity Error	E _{SENS(PS)}	V _{CC} @ V _{CC(MIN)} or V _{CC(MAX)}		-1.5	_	1.5	%
Common-Mode Field Rejection	CMFR	Input-referred error due to common-mod	de field	-	4	_	mA/G

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400 kHz, High Accuracy Current Sensor with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

COMMON PERFORMANCE CHARACTERISTICS (VREF, FAULT, GAIN_SEL): Valid through full operating temperature range, T_A = - 40°C to 150°C, C_{BYPASS} = 0.1 µF, and V_{CC} = 5 V or 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
REFERENCE OUTPUT CHAR	ACTERISTIC	CS (VREF)		·		
Zero Current Reference Voltage	V	Bidirectional; V _{CC} = 5 V	2.49	2.5	2.51	V
	V _{REF(BI)}	Bidirectional; V _{CC} = 3.3 V	1.64	1.65	1.66	V
Zero Current Reference voltage	N	Unidirectional; V _{CC} = 5 V	0.49	0.5	0.51	V
	V _{REF(UNI)}	Unidirectional; V_{CC} = 3.3 V	0.32	0.33	0.34	V
Reference Source Current Limit	I _{REF(SRC)}	Maximum current V_{REF} can passively source	-	25	_	mA
Reference Source Current Limit	I _{REF(SNK)}	Maximum current V_{REF} can passively sink	_	-25	_	mA
Reference Slew Rate	SR _{REF}	C_{VREF} = 0 nF, R_{VREF} = 0 Ω	0.8	-	_	V/µs
OVERCURRENT FAULT CH	ARACTERIS	STICS (OCF)				
OCF On Voltage [3]	V _{FAULT-ON}	R_{PU} = 4.7 k Ω , under fault condition	_	0.07	0.4	V
OCF Sink Current [3]	I _{OCF(SNK)}	No Fault	_	100	-	nA
		Fault Assertion	0.01	-	1.1	mA
	V _{VOC}	V _{CC} = 5 V	0.5	_	2	V
VOC Operating Voltage Range		V _{CC} = 3.3 V	0.33	_	1.32	V
Fault Error	E _{OCF}		-10	±3	10	%I _{OCF-OP}
OOF Ukustanaaja		V _{CC} = 5 V	_	6	_	%FS
OCF Hysteresis	I _{OCF(HYS)}	V _{CC} = 3.3 V		9	_	%FS
OCF Reaction Time [3]	t _{OCF-R}	Time from I_{OCF-OP} , with a 1.2 × I_{OCF-OP} until fault asserts	_	1	1.5	μs
OCF Mask [3]	t _{OCF-MASK}	Time I _{OCF-OP} must be present after t _{OCF-R} for fault assertion [3]	0	0	3	μs
OCF Response Time [3]	t _{OCF}	t _{OCF-MASK} = 0 μs	_	1	1.5	μs
OCF Hold Time [3]	t _{OCF-HOLD}	Minimum duration of FAULT assertion ^[2]	0	0	5	ms
GAIN SELECTION PIN CHA	RACTERIST	TICS (GAIN_SEL0, GAIN_SEL1)				
Gain Select Internal Resistor	R _{GSint}		_	1	_	MΩ
		V _{CC} = 5 V	3.75	-	_	V
GAIN_SEL Logic Input Voltage	V _{H(SEL)}	V _{CC} = 3.3 V	2.25	_	_	V
	V _{L(SEL)}		_	_	0.5	V
Leakage Current [3]	I _{SEL(SNK)}		_	_	±10	μA

[1] V_{CC} rate +1 V/ms, for best accuracy.
 [2] Typical value is factory default.

^[3] Guaranteed by design and bench validated



ACS37002LMABTR-050B5-M

ACS37002LMABTR-050B5-	S37002LMABTR-050B5-M Gain_Sel Pin Performance Key						
Parameter (Units)	arameter (Units) Gain_Sel_1 (Boolean) Gain_Sel_0 (Boolean) Sens (mV/A)						
Туре	Digital Input	Digital Input	Calculation	Bidirectional			
	0	0	40	50			
Selection	0	1	50	40			
Combination	1	0	60	33.3			
	1	1	30	66.7			

ACS37002LMABTR-050B5-M PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, $T_A = -40^{\circ}$ C to 150°C, $C_{BYPASS} = 0.1 \,\mu$ F, and $V_{CC} = 5 V$, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE		* 				
		Gain Sel 00	-50	_	50	A
Ourset Consist Donat		Gain Sel 01	-40	-	40	A
Current Sensing Range	I _{PR}	Gain Sel 10	-33.3	-	33.3	A
		Gain Sel 11	-66.7	-	66.7	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	40	-	mV/A
Sonoitivity	Sens	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	50	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	60	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	30	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; $I_P = 0 A$, $T_A = 25^{\circ}C$	-	2.5	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDE} AND TOTAL ERROR COMPONENTS	_{AL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	I _P = I _{PR(max)}	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-1.5	-0.5 ±0.6	1.5	%
	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$		-2 ±3	10	mV
Zero Current Reference Error		$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-8	-1 ±4	8	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-8	-1 ±3	8	mV
QVO Error	V	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-3 ±5	10	mV
QVO Elloi	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	-1 ±4	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS IN	CLUDING LIFETIME DRIFT [2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	I _P = I _{PR(max)}	-3.6	-1.6 ±1.2	3.6	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-3.4	-1.5 ±1.1	3.4	%
Zero Current Reference Error Including		$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = 25^{\circ}$ C to 150°C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-2 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, I _P = 0 A, T _A = 25°C to 150°C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	±4	10	mV
	N	$V_{IOUT(Q)}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	±7	10	mV

[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.
 [2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.
 [3] Lifetime drift characteristics are based on a statistical combination of production distributions and worst case distribution of parametric drift of individuals observed during AEC-Q100 qualification.



ACS37002LMABTR-066B5-M

ACS37002LMABTR-066B5-N	Selection Identifier			
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)		
Туре	Digital Input	Digital Input	Calculation	Bidirectional
	0	0	30	66.7
Selection	0	1	25	80
Combination	1	0	20	100
	1	1	15	133.3

ACS37002LMABTR-066B5-M PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 µF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE		·		·		
		Gain Sel 00	-66.7	_	66.7	А
		Gain Sel 01	-80	-	80	А
Current Sensing Range	I _{PR}	Gain Sel 10	-100	-	100	А
		Gain Sel 11	-133.3	-	133.3	А
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	30	-	mV/A
Sensitivity	Sens	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	25	-	mV/A
Sensitivity	Sells	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	20	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	15	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; $I_P = 0 A$, $T_A = 25^{\circ}C$	-	2.5	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDE} AND TOTAL ERROR COMPONENTS	_{AL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	I _P = I _{PR(max)}	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-1.5	-0.5 ±0.6	1.5	%
Zero Current Reference Error		$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-10	-2 ±3	10	mV
Zero Current Relefence Error	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-8	-1 ±4	8	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-8	-1 ±3	8	mV
QVO Error	N	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-3 ±5	10	mV
	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = -40^{\circ}C$ to $25^{\circ}C$	-10	-1 ±4	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS IN	CLUDING LIFETIME DRIFT [2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	I _P = I _{PR(max)}	-3.6	-1.6 ±1.2	3.6	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-3.4	-1.5 ±1.1	3.4	%
Zero Current Reference Error Including	V	$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-2 ±3	10	mV
Offset Error Including Lifetime Drift	V	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-10	-2 ±5	10	mV
	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	±4	10	mV
	N	$V_{IOUT(Q)}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.

[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.
[3] Lifetime drift characteristics are based on a statistical combination of production distributions and worst case distribution of parametric drift of individuals observed during AEC-Q100 qualification.



ACS37002LMABTR-050U5-M

ACS37002LMABTR-050U5-M	Selection Identifier			
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)		
Туре	Digital Input	Digital Input	Calculation	Unidirectional
	0	0	80	50
Selection	0	1	100	40
Combination	1	0	120	33.3
	1	1	60	66.7

ACS37002LMABTR-050U5-M PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 µF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. ^[1]	Max.	Units
NOMINAL PERFORMANCE				· · · · · · · · · · · · · · · · · · ·		
		Gain Sel 00	0	-	50	A
		Gain Sel 01	0	-	40	А
Current Sensing Range	I _{PR}	Gain Sel 10	0	-	33.3	А
		Gain Sel 11	0	-	66.7	А
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	80	-	mV/A
Constitution	Sama	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	100	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	120	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	60	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	25	50	100	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Unidirectional; I _P = 0 A, T _A = 25°C	-	0.5	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(ID} AND TOTAL ERROR COMPONENTS	_{EAL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	I _P = I _{PR(max)}	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-1.5	-0.5 ±0.6	1.5	%
Zero Current Reference Error	N	$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-2 ±3	10	mV
Zelo Current Relefence Enoi	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
Offset Error		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-8	-1 ±4	8	mV
Oliset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-8	-1 ±3	8	mV
QVO Error	V	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-3 ±5	10	mV
QVO Elloi	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = -40^{\circ}C$ to 25°C	-10	-1 ±4	10	mV
TOTAL ERROR AND TOTAL ERROR CO	OMPONENTS IN	CLUDING LIFETIME DRIFT ^[2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	I _P = I _{PR(max)}	-3.6	-1.6 ±1.2	3.6	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_{P} = I_{PR(max)}$, $T_{A} = 25^{\circ}$ C to 150°C or -40°C to 25°C	-3.4	-1.5 ±1.1	3.4	%
Zero Current Reference Error Including		$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-2 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	±4	10	mV
OVO Free Including Lifetime Drift	N	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma. ^[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.



ACS37002LMABTR-066U5-M

ACS37002LMABTR-066U5-N	Selection Identifier			
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)		
Туре	Digital Input	Digital Input	Calculation	Unidirectional
	0	0	60	66.7
Selection	0	1	50	80
Combination	1	0	40	100
	1	1	30	133.3

ACS37002LMABTR-066U5-M PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 µF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE		·		· · · · · · · · · · · · · · · · · · ·		
		Gain Sel 00	0	-	66.7	A
		Gain Sel 01	0	-	80	A
Current Sensing Range	I _{PR}	Gain Sel 10	0	-	100	A
		Gain Sel 11	0	-	133.3	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	60	_	mV/A
		Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	50	_	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	40	_	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	30	_	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	25	50	100	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Unidirectional; $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$	-	0.5	_	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(ID} AND TOTAL ERROR COMPONENTS	_{EAL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	$I_P = I_{PR(max)}$	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-1.5	-0.5 ±0.6	1.5	%
		$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-2 ±3	10	mV
Zero Current Reference Error	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_{P} = 0$ A, $T_{A} = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-8	-1 ±4	8	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-8	-1 ±3	8	mV
		V _{IOUT(Q)} , I _P = 0 A, T _A = 25°C to 150°C	-10	-3 ±5	10	mV
QVO Error	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	-1 ±4	10	mV
TOTAL ERROR AND TOTAL ERROR CO	OMPONENTS IN	CLUDING LIFETIME DRIFT ^[2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	$I_{P} = I_{PR(max)}$	-3.6	-1.6 ±1.2	3.6	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_{P} = I_{PR(max)}, T_{A} = 25^{\circ}C \text{ to } 150^{\circ}C \text{ or } -40^{\circ}C \text{ to } 25^{\circ}C$	-3.4	-1.5 ±1.1	3.4	%
Zero Current Reference Error Including		$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = 25^{\circ}\text{C}$ to 150°C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-2 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±4	10	mV
OV/O Error Including Lifetime Drift		$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

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ACS37002LMABTR-050B3

ACS37002LMABTR-050B3 Ga	Selection Identifier				
Parameter (Units)	ameter (Units) Gain_Sel_1 (Boolean) Gain_Sel_0 (Boolean) Sens (mV/A)				
Туре	Digital Input	Digital Input	Calculation	Bidirectional	
	0	0	26.4	50	
Selection	0	1	33	40	
Combination	1	0	39.6	33.3	
	1	1	19.8	66.7	

ACS37002LMABTR-050B3 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 $\mu\text{F},$ and V_{CC} = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE		·				
		Gain Sel 00	-50	_	50	A
Oursent Consists Downs		Gain Sel 01	-40	-	40	A
Current Sensing Range	I _{PR}	Gain Sel 10	-33.3	-	33.3	A
		Gain Sel 11	-66.7	-	66.7	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	26.4	-	mV/A
Sensitivity	Sens	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	33	-	mV/A
Sensitivity	Selis	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	39.6	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	19.8	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; $I_P = 0 A$, $T_A = 25^{\circ}C$	-	1.65	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDE} AND TOTAL ERROR COMPONENTS	_{EAL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	I _P = I _{PR(max)}	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or $-40^{\circ}C$ to 25°C	-1.5	-0.5 ±0.6	1.5	%
7 0 107 5	N/	$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-2 ±3	10	mV
Zero Current Reference Error	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
Offset Error		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-8	-1 ±4	8	mV
Oliset Elfor	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-8	-1 ±3	8	mV
QVO Error	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-10	-3 ±5	10	mV
	V QE	$V_{IOUT(Q)}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-1 ±4	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS IN	CLUDING LIFETIME DRIFT [2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	I _P = I _{PR(max)}	-3.6	-1.6 ±1.2	3.6	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_{P} = I_{PR(max)}, T_{A} = 25^{\circ}C \text{ to } 150^{\circ}C \text{ or } -40^{\circ}C \text{ to } 25^{\circ}C$	-3.4	-1.5 ±1.1	3.4	%
Zero Current Reference Error Including		$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = -40^{\circ}$ C to 25°C	-10	-2 ±3	10	mV
Offect Error Including Lifetime Drift		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	±4	10	mV
QVO Error Including Lifetime Drift	V.	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-14	-4 ±6	14	mV
	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma. ^[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.



ACS37002LMABTR-066B3

ACS37002LMABTR-066B3 G	S37002LMABTR-066B3 Gain_Sel Pin Performance Key					
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)				
Туре	Digital Input	Digital Input	Calculation	Bidirectional		
	0	0	19.8	66.7		
Selection	0	1	16.5	80		
Combination	1	0	13.2	100		
	1	1	9.9	133.3		

ACS37002LMABTR-066B3 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 $\mu\text{F},$ and V_{CC} = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE		•		· · · · · · · · · · · · · · · · · · ·		
		Gain Sel 00	-66.7	-	66.7	A
		Gain Sel 01	-80	-	80	A
Current Sensing Range	I _{PR}	Gain Sel 10	-100	-	100	A
		Gain Sel 11	-133.3	-	133.3	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	19.8	_	mV/A
Constitute	Cana	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	16.5	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	13.2	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	9.9	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; I _P = 0 A, T _A = 25°C	-	1.65	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDE} AND TOTAL ERROR COMPONENTS	AL) × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	I _P = I _{PR(max)}	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-1.5	-0.5 ±0.6	1.5	%
Zero Current Reference Error	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_{P} = 0 A$, $T_{A} = 25^{\circ}C$ to $150^{\circ}C$	-10	-2 ±3	10	mV
		$V_{REFactual} - V_{REFideal}$, $I_{P} = 0$ A, $T_{A} = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
Offset Error	N	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-8	-1 ±4	8	mV
Oliset Elloi	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-8	-1 ±3	8	mV
QVO Error	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-3 ±5	10	mV
	V QE	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = -40^{\circ}C$ to 25°C	-10	-1 ±4	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS IN	CLUDING LIFETIME DRIFT ^[2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	$I_{P} = I_{PR(max)}$	-3.6	-1.6 ±1.2	3.6	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_{P} = I_{PR(max)}, T_{A} = 25^{\circ}C \text{ to } 150^{\circ}C \text{ or } -40^{\circ}C \text{ to } 25^{\circ}C$	-3.4	-1.5 ±1.1	3.4	%
Zero Current Reference Error Including		$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = 25^{\circ}$ C to 150°C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	-2 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±4	10	mV
	N	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.

[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.



ACS37002LMABTR-050U3

ACS37002LMABTR-050U3	S37002LMABTR-050U3 Gain_Sel Pin Performance Key					
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)				
Туре	Digital Input	Digital Input	Calculation	Unidirectional		
	0	0	52.8	50		
Selection	0	1	66	40		
Combination	1	0	79.2	33.3		
	1	1	39.6	66.7		

ACS37002LMABTR-050U3 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 µF, and V_{CC} = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE		·		· · · · · · · · · · · · · · · · · · ·		
		Gain Sel 00		-	50	A
Current Sensing Benge		Gain Sel 01	0	-	40	A
Current Sensing Range	I _{PR}	Gain Sel 10	0	-	33.3	A
		Gain Sel 11	0	-	66.7	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	52.8	-	mV/A
	0	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	66	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	79.2	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	39.6	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	25	50	100	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Unidirectional; I _P = 0 A, T _A = 25°C	-	0.33	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDE} AND TOTAL ERROR COMPONENTS	_{AL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	I _P = I _{PR(max)}	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-1.5	-0.5 ±0.6	1.5	%
	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_{P} = 0 A$, $T_{A} = 25^{\circ}C$ to 150°C	-10	-2 ±3	10	mV
Zero Current Reference Error		$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
Offset Error		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-8	-1 ±4	8	mV
Oliset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-8	-1 ±3	8	mV
QVO Error	N/	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-3 ±5	10	mV
	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = -40^{\circ}C$ to $25^{\circ}C$	-10	-1 ±4	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS IN	CLUDING LIFETIME DRIFT ^[2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	$I_{P} = I_{PR(max)}$	-3.6	-1.6 ±1.2	3.6	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_{P} = I_{PR(max)}$, $T_{A} = 25^{\circ}$ C to 150°C or -40°C to 25°C	-3.4	-1.5 ±1.1	3.4	%
Zero Current Reference Error Including		$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150°C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = -40^{\circ}$ C to 25°C	-10	-2 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150°C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	±4	10	mV
OVO Franklanding Lifetime Drift	N	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma. ^[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.



ACS37002LMABTR-066U3

ACS37002LMABTR-066U3	Selection Identifier			
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)		
Туре	Digital Input	Digital Input	Calculation	Unidirectional
	0	0	39.6	66.7
Selection	0	1	33	80
Combination	1	0	26.4	100
	1	1	19.8	133.3

ACS37002LMABTR-066U3 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 $\mu\text{F},$ and V_{CC} = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions		Typ. [1]	Max.	Units
NOMINAL PERFORMANCE						<u>`</u>
		Gain Sel 00		-	66.7	A
		Gain Sel 01	0	-	80	A
Current Sensing Range	I _{PR}	Gain Sel 10	0	-	100	A
		Gain Sel 11	0	-	133.3	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	39.6	-	mV/A
Consitivity	Sama	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	33	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	26.4	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	19.8	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	25	50	100	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Unidirectional; I _P = 0 A, T _A = 25°C	-	0.33	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDI} AND TOTAL ERROR COMPONENTS	_{EAL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	$I_{P} = I_{PR(max)}$	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-1.5	-0.5 ±0.6	1.5	%
	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-10	-2 ±3	10	mV
Zero Current Reference Error		$V_{REFactual} - V_{REFideal}$, $I_{P} = 0$ A, $T_{A} = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-8	-1 ±4	8	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-8	-1 ±3	8	mV
QVO Error	N	V _{IOUT(Q)} , I _P = 0 A, T _A = 25°C to 150°C	-10	-3 ±5	10	mV
QVO Ellor	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	-1 ±4	10	mV
TOTAL ERROR AND TOTAL ERROR CO	OMPONENTS IN	CLUDING LIFETIME DRIFT ^[2,3]				
Total Error Including Lifetime Drift	E _{TOT LTD}	$I_{P} = I_{PR(max)}$	-3.6	-1.6 ±1.2	3.6	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to 150°C or -40°C to 25°C	-3.4	-1.5 ±1.1	3.4	%
Zero Current Reference Error Including		$V_{REFactual} - V_{REFideal}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	-2 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	±4	10	mV
OVO Freeze Including Lifetime Drift		$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.

[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.



ACS37002KMABTR-050B5-M

AACS37002KMABTR-050	Selection Identifier			
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)		
Туре	Digital Input	Digital Input	Calculation	Bidirectional
	0	0	40	50
Selection	0	1	50	40
Combination	1	0	60	33.3
	1	1	30	66.7

ACS37002KMABTR-050B5-M PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 125°C, C_{BYPASS} = 0.1 µF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE	·			· · · · · · · · ·		
		Gain Sel 00	-50	_	50	A
		Gain Sel 01	-40	-	40	A
Current Sensing Range	I _{PR}	Gain Sel 10	-33.3	-	33.3	A
		Gain Sel 11	-66.7	-	66.7	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	40	-	mV/A
Constitution	Sama	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	50	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	60	_	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	30	_	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; $I_P = 0 A$, $T_A = 25^{\circ}C$	-	2.5	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDE} AND TOTAL ERROR COMPONENTS	_{EAL)} × I _{PR} +V _{REF}))	/ (Sens _(IDEAL) × I _{PR})× 100				
Total Error	E _{TOT}	$I_{P} = I_{PR(max)}$	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_{P} = I_{PR(max)}$, $T_{A} = 25^{\circ}$ C to 125°C, $T_{A} = -40^{\circ}$ C to 25°C	-1	-0.3 ±0.5	1	%
	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $125^{\circ}C$	-10	-2 ±3	10	mV
Zero Current Reference Error		$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
011 15		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125° C	-8	±5	8	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-8	-1 ±3	8	mV
QVO Error		$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C	-10	-3 ±4	10	mV
QVO EIIO	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±5	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS IN	CLUDING LIFETIME DRIFT ^[2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	I _P = I _{PR(max)}	-3.4	-1.4 ±1.2	3.4	%
Sensitivity Error Including Lifetime Drift	E _{SENS LTD}	$I_{P} = I_{PR(max)}$, $T_{A} = 25^{\circ}$ C to 125°C or -40°C to 25°C	-3.2	-1.3 ±1.1	3.2	%
Zero Current Reference Error Including		$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = 25^{\circ}$ C to 125°C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = -40^{\circ}C$ to 25°C	-10	-2 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{\text{IOUT}(Q)} - V_{\text{REF}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = -40^{\circ}$ C to 25°C	-10	±4	10	mV
		$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.
 [2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.



ACS37002KMABTR-050B3

ACS37002KMABTR-050B	CS37002KMABTR-050B3 Gain_Sel Pin Performance Key					
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)				
Туре	Digital Input	Digital Input	Calculation	Bidirectional		
	0	0	26.4	50		
Selection	0	1	33	40		
Combination	1	0	39.6	33.3		
	1	1	19.8	66.7		

ACS37002KMABTR-050B3 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 125°C, C_{BYPASS} = 0.1 $\mu\text{F},$ and V_{CC} = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE	·			· · · · · · · · · · · · · · · · · · ·		
		Gain Sel 00		-	50	A
Current Consing Dance		Gain Sel 01	-40	-	40	А
Current Sensing Range	I _{PR}	Gain Sel 10	-33.3	-	33.3	А
		Gain Sel 11	-66.7	-	66.7	А
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	26.4	-	mV/A
Constitute	Sama	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	33	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	39.6	_	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	19.8	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; $I_P = 0 A$, $T_A = 25^{\circ}C$	-	1.65	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDE} AND TOTAL ERROR COMPONENTS	_{EAL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	I _P = I _{PR(max)}	-1.75	-0.5 ±0.6	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to $125^{\circ}C$, $T_A = -40^{\circ}C$ to $25^{\circ}C$	-1	-0.3 ±0.5	1	%
	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125° C	-10	-2 ±3	10	mV
Zero Current Reference Error		$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = -40^{\circ}$ C to 25°C	-10	-1 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C	-8	±5	8	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-8	-1 ±3	8	mV
QVO Error	V	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $125^{\circ}C$	-10	-3 ±4	10	mV
QVO Elloi	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±5	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS IN	CLUDING LIFETIME DRIFT ^[2,3]				
Total Error Including Lifetime Drift	E _{TOT_LTD}	I _P = I _{PR(max)}	-3.4	-1.4 ±1.2	3.4	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to $125^{\circ}C$ or $-40^{\circ}C$ to $25^{\circ}C$	-3.2	-1.3 ±1.1	3.2	%
Zero Current Reference Error Including		$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = 25^{\circ}$ C to 125° C	-10	-3 ±4	10	mV
Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 A$, $T_A = -40^{\circ}C$ to 25°C	-10	-2 ±3	10	mV
		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125° C	-10	-2 ±5	10	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-10	±4	10	mV
OVO Error Including Lifetime Drift	V	$V_{IOUT(Q)}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125° C	-14	-4 ±6	14	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±7	10	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.

[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.



ACS37002LLAATR-015B5

ACS37002LLAATR-015B5	Selection Identifier			
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)		
Туре	Digital Input	Digital Input	Calculation	Bidirectional
	0	0	133.3	15
Selection	0	1	166.6	12
Combination	1	0	200	10
	1	1	100	20

ACS37002LLAATR-015B5 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 µF, and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions		Typ. [1]	Max.	Units
NOMINAL PERFORMANCE		· · · · · · · · · · · · · · · · · · ·				
		Gain Sel 00	-15	_	15	A
		Gain Sel 01	-12	-	12	А
Current Sensing Range	I _{PR}	Gain Sel 10	-10	-	10	A
		Gain Sel 11	-20	_	20	А
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	133.3	_	mV/A
Constitute	Sens	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	166.6	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	200	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	_	100	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; I _P = 0 A, T _A = 25°C	-	2.5	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(ID} AND TOTAL ERROR COMPONENTS	_{EAL)} × I _{PR} + V _{REF}))) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	$I_P = I_{PR(max)}, T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-1.75	±1.2	1.75	%
		$I_P = I_{PR(max)}$, $T_A = -40^{\circ}C$ to 25°C		±1.4	1.75	%
Sensitivity Error	E _{SENS}	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to $150^{\circ}C$, $T_A = -40^{\circ}C$ to $25^{\circ}C$	-1.5	±1.2	1.5	%
Zero Current Reference Error	V _{RE}	$V_{REFactual}-V_{REFideal},\ I_P$ = 0 A, T_A = 25°C to 150°C, T_A = -40°C to 25°C	-10	±3	10	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}, I_P$ = 0 A, T_A = 25°C to 150°C, T_A = -40°C to 25°C	-8	±5	8	mV
QVO Error	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C , $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±5	10	mV
TOTAL ERROR AND TOTAL ERROR CO	OMPONENTS IN	CLUDING LIFETIME DRIFT [2][3]				
Total Error Including Lifetime Drift		$I_P = I_{PR(max)}, T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-3.7	-0.7 ±1.8	3.7	%
Total Error Including Lifetime Drift	E _{TOT_LTD}	$I_P = I_{PR(max)}, T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	-3.5	-0.5 ±1.9	3.5	%
Sensitivity Error Including Lifetime Drift	F	$I_P = I_{PR(max)}, T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-3.5	-0.8 ±1.6	3.5	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_P = I_{PR(max)}, T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	-3.4	-0.5 ±1.8	3.4	%
Zero Current Reference Error Including Lifetime Drift	V _{RE_LTD}	$V_{REFactual}-V_{REFideal},\ I_P$ = 0 A, T_A = 25°C to 125°C, T_A = -40°C to 25°C	-11	±7	11	mV
Offect Error Including Lifetime Drift	N	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125° C	-15	2 ±7	15	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-11	±7	11	mV
OVO Error Including Lifetime Drift	N	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C	-17	±9	17	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-14	±8	14	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.

[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.
 [3] Lifetime drift characteristics are based on a statistical combination of production distributions and worst case distribution of parametric drift of individuals observed during AEC-Q100 qualification.



ACS37002LLAATR-025B5

ACS37002LLAATR-025B5	CS37002LLAATR-025B5 Gain_Sel Pin Performance Key					
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)				
Туре	Digital Input	Digital Input	Calculation	Bidirectional		
	0	0	80	25		
Selection	0	1	66.6	30		
Combination	1	0	53.3	37.5		
	1	1	40	50		

ACS37002LLAATR-025B5 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, $T_A = -40^{\circ}$ C to 150°C, C_{BYPASS} = 0.1 $\mu\text{F},$ and V_{CC} = 5 V, unless otherwise specified

Characteristic	Symbol	Test Conditions		Typ. [1]	Max.	Units
NOMINAL PERFORMANCE				· · · · · · · · · · · · · · · · · · ·		
		Gain Sel 00		_	25	A
		Gain Sel 01	-30	_	30	A
Current Sensing Range	I _{PR}	Gain Sel 10	-37.5	_	37.5	A
		Gain Sel 11	-50	-	50	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	80	-	mV/A
	0	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	_	66.6	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	53.3	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	_	40	_	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; $I_P = 0 A$, $T_A = 25^{\circ}C$	_	2.5	_	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(ID} AND TOTAL ERROR COMPONENTS) / (Sens _(IDEAL) × I _{PR}) × 100				
Total Error	E _{TOT}	$I_P = I_{PR(max)}, T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-1.75	±1.2	1.75	%
		$I_P = I_{PR(max)}$, $T_A = -40^{\circ}C$ to 25°C	-1.75	±1.4	1.75	%
Sensitivity Error	E _{SENS}	$I_{P} = I_{PR(max)}$, $T_{A} = 25^{\circ}C$ to 150°C, $T_{A} = -40^{\circ}C$ to 25°C		±1.2	1.5	%
Zero Current Reference Error	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150°C, $T_A = -40^{\circ}$ C to 25°C	-10	±3	10	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C, $T_A = -40^{\circ}$ C to 25° C	-8	±5	8	mV
QVO Error	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 A$, $T_A = 25^{\circ}C$ to $150^{\circ}C$, $T_A = -40^{\circ}C$ to $25^{\circ}C$	-10	±5	10	mV
TOTAL ERROR AND TOTAL ERROR CO	OMPONENTS IN	CLUDING LIFETIME DRIFT [2][3]				
Tatal Francisco Includio a Lifetina a Drift		$I_P = I_{PR(max)}, T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-3.7	-0.7 ±1.8	3.7	%
Total Error Including Lifetime Drift	E _{TOT_LTD}	$I_P = I_{PR(max)}, T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	-3.5	-0.5 ±1.9	3.5	%
		$I_{P} = I_{PR(max)}, T_{A} = 25^{\circ}C \text{ to } 150^{\circ}C$	-3.5	-0.8 ±1.6	3.5	%
Sensitivity Error Including Lifetime Drift	E _{SENS_LTD}	$I_P = I_{PR(max)}, T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	-3.4	-0.5 ±1.8	3.4	%
Zero Current Reference Error Including Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125°C, $T_A = -40^{\circ}$ C to 25°C	-11	±7	11	mV
Offect Freez Including Lifetime Drift		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C	-15	2 ±7	15	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-11	±7	11	mV
		$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C	-17	±9	17	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-14	±8	14	mV

[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.
 [2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.
 [3] Lifetime drift characteristics are based on a statistical combination of production distributions and worst case distribution of parametric drift of individuals observed during AEC-Q100 qualification.



ACS37002LLAATR-015B3

ACS37002LLAATR-015B3	CS37002LLAATR-015B3 Gain_Sel Pin Performance Key					
Parameter (Units)	Gain_Sel_1 (Boolean)	Max IP (A)				
Туре	Digital Input	Digital Input	Calculation	Bidirectional		
	0	0	88	15		
Selection	0	1	110	12		
Combination	1	0	132	10		
	1	1	66	20		

ACS37002LLAATR-015B3 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, T_A = -40°C to 150°C, C_{BYPASS} = 0.1 $\mu\text{F},$ and V_{CC} = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE		·				
Current Sensing Range		Gain Sel 00	-15		15	A
		Gain Sel 01	-12	-	12	A
	I _{PR}	Gain Sel 10	-10	-	10	A
		Gain Sel 11	-20	-	20	A
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	88	-	mV/A
Sensitivity	Sens	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	110	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	132	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	66	-	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	50	100	200	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Bidirectional; $I_P = 0 A$, $T_A = 25^{\circ}C$	-	1.65	-	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDI} AND TOTAL ERROR COMPONENTS	_{EAL)} × I _{PR} + V _{REF})) / (Sens _(IDEAL) × I _{PR}) × 100				
	_	$I_P = I_{PR(max)}, T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-1.75	±1.2	1.75	%
Total Error	E _{TOT}	$I_P = I_{PR(max)}, T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	-1.75	±1.4	1.75	%
Sensitivity Error	E _{SENS}	$I_{P} = I_{PR(max)}, T_{A} = 25^{\circ}C \text{ to } 150^{\circ}C, T_{A} = -40^{\circ}C \text{ to } 25^{\circ}C$	-1.5	±1.2	1.5	%
Zero Current Reference Error	V _{RE}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C , $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±3	10	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, I _P = 0 A, T _A = 25°C to 150°C, T _A = -40°C to 25°C	-8	±5	8	mV
QVO Error	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C , $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±5	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS IN					
Total Error Including Lifetime Drift		$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-3.7	-0.7 ±1.8	3.7	%
	E _{TOT_LTD}	$I_P = I_{PR(max)}$, $T_A = -40^{\circ}C$ to 25°C	-3.5	-0.5 ±1.9	3.5	%
Sensitivity Error Including Lifetime Drift	_	$I_P = I_{PR(max)}$, $T_A = 25^{\circ}C$ to $150^{\circ}C$	-3.5	-0.8 ±1.6	3.5	%
	E _{SENS_LTD}	$I_P = I_{PR(max)}, T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	-3.4	-0.5 ±1.8	3.4	%
Zero Current Reference Error Including Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C , $T_A = -40^{\circ}\text{C}$ to 25°C	-11	±7	11	mV
	N/	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125° C	-15	2 ±7	15	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-11	±7	11	mV
	N/	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C	-17	±9	17	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-14	±8	14	mV

^[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.

[2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.
 [3] Lifetime drift characteristics are based on a statistical combination of production distributions and worst case distribution of parametric drift of individuals observed during AEC-Q100 qualification.



ACS37002LLAATR-025U3

ACS37002LLAATR-025U3 Gain_Sel Pin Performance Key			Selection Identifier	
Parameter (Units)	Gain_Sel_1 (Boolean)	Gain_Sel_0 (Boolean)	Sens (mV/A)	Max IP (A)
Туре	Digital Input	Digital Input	Calculation	Unidirectional
Selection Combination	0	0	105.6	25
	0	1	88	30
	1	0	70.4	37.5
	1	1	52.8	50

ACS37002LLAATR-025U3 PERFORMANCE CHARACTERISTICS: Valid through full operating temperature range, $T_A = -40^{\circ}$ C to 150°C, C_{BYPASS} = 0.1 $\mu\text{F},$ and V_{CC} = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Typ. [1]	Max.	Units
NOMINAL PERFORMANCE						
		Gain Sel 00	0	-	25	A
		Gain Sel 01	0	-	30	25 A 30 A 37.5 A 50 A - mV/A - mV/A - mV/A - mV/A - mV/A - mV/A 100 %FS 10 mV 8 mV 10 mV 3.7 % 3.5 %
Current Sensing Range	I _{PR}	Gain Sel 10	0	-	37.5	A
		Gain Sel 11	0	-	50	А
		Gain Sel 00; I _{PR(min)} < I _P < I _{PR(max)}	-	105.6	_	mV/A
	0	Gain Sel 01; I _{PR(min)} < I _P < I _{PR(max)}	-	88	-	mV/A
Sensitivity	Sens	Gain Sel 10; I _{PR(min)} < I _P < I _{PR(max)}	-	70.4	-	mV/A
		Gain Sel 11; I _{PR(min)} < I _P < I _{PR(max)}	-	52.8	_	mV/A
Overcurrent Fault Operating Range	I _{OCF-OR}	Typ. = factory-programmed default, FS = Full-Scale	25	50	100	%FS
Zero Current Output Voltage	V _{IOUT(Q)}	Unidirectional; I _P = 0 A, T _A = 25°C	-	0.33	_	V
TOTAL ERROR (V _{IOUT(ACTUAL)} – (Sens _{(IDI} AND TOTAL ERROR COMPONENTS		/ (Sens _(IDEAL) × I _{PR}) × 100	·			
	_	$I_{P} = I_{PR(max)}, T_{A} = 25^{\circ}C \text{ to } 150^{\circ}C$	-1.75	±1.2	1.75	%
Total Error	E _{TOT}	$I_P = I_{PR(max)}, T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	-1.75	±1.4	1.75	%
Sensitivity Error	E _{SENS}	$I_{P} = I_{PR(max)}$, $T_{A} = 25^{\circ}C$ to 150°C, $T_{A} = -40^{\circ}C$ to 25°C	-1.5	±1.2	1.5	%
Zero Current Reference Error	V _{RE}	$V_{\text{REFactual}} - V_{\text{REFideal}}$, $I_{\text{P}} = 0$ A, $T_{\text{A}} = 25^{\circ}$ C to 150°C, $T_{\text{A}} = -40^{\circ}$ C to 25°C	-10	±3	10	mV
Offset Error	V _{OE}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 150° C, $T_A = -40^{\circ}$ C to 25° C	-8	±5	8	mV
QVO Error	V _{QE}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 150°C , $T_A = -40^{\circ}\text{C}$ to 25°C	-10	±5	10	mV
TOTAL ERROR AND TOTAL ERROR CO	MPONENTS INC	LUDING LIFETIME DRIFT [2][3]		· · · · · · · · · · · · · · · · · · ·		
		$I_{P} = I_{PR(max)}, T_{A} = 25^{\circ}C \text{ to } 150^{\circ}C$	-3.7	-0.7 ±1.8	3.7	%
Total Error Including Lifetime Drift	E _{TOT_LTD}	$I_P = I_{PR(max)}$, $T_A = -40^{\circ}$ C to 25°C	-3.5	-0.5 ±1.9	3.5	%
Sensitivity Error Including Lifetime Drift	_	$I_{\rm P} = I_{\rm PR(max)}, T_{\rm A} = 25^{\circ}{\rm C} \text{ to } 150^{\circ}{\rm C}$	-3.5	-0.8 ±1.6	3.5	%
	E _{SENS_LTD}	$I_P = I_{PR(max)}$, $T_A = -40^{\circ}$ C to 25°C	-3.4	-0.5 ±1.8	3.4	%
Zero Current Reference Error Including Lifetime Drift	V _{RE_LTD}	$V_{REFactual} - V_{REFideal}$, $I_P = 0 \text{ A}$, $T_A = 25^{\circ}\text{C}$ to 125°C , $T_A = -40^{\circ}\text{C}$ to 25°C	-11	±7	11	mV
Offect From Including Lifetime Drift		$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125° C	-15	2 ±7	15	mV
Offset Error Including Lifetime Drift	V _{OE_LTD}	$V_{IOUT(Q)} - V_{REF}$, $I_P = 0$ A, $T_A = -40^{\circ}$ C to 25°C	-11	±7	11	mV
		$V_{IOUT(Q)}$, $I_P = 0$ A, $T_A = 25^{\circ}$ C to 125° C	-17	±9	17	mV
QVO Error Including Lifetime Drift	V _{QE_LTD}	$V_{IOUT(Q)}$, $I_P = 0 \text{ A}$, $T_A = -40^{\circ}\text{C}$ to 25°C	-14	±8	14	mV

[1] Typicals values are the mean ±3 sigma of production distributions. These are formatted as mean ±3 sigma.
 [2] Typicals values are the mean ±3 sigma statistical combination of production and AEC-Q100 individual drift distributions. These are formatted as mean ±3 sigma.



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

FUNCTIONAL DESCRIPTION

Power-On Reset Operation

The descriptions in this section assume: temperature = 25° C, with the labeled test conditions. The provided graphs in this section show V_{IOUT} moving with V_{CC}. The voltage of V_{IOUT} during a high-impedance state will be most consistent with a known load (R_L,C_L).

POWER-ON/POWER-OFF

As V_{CC} ramps up, the V_{IOUT} and V_{REF} outputs are high impedance until V_{CC} reaches and passes $V_{POR(H)}$ [1] in Figure 4. V_{REF} and V_{IOUT} will continue to report until V_{CC} is less than $V_{POR(L)}$ [5] in Figure 4, at which point they will go high impedance. Note that the time it takes the output to reach a steady state will depend on the external circuitry used.

POWER-ON DELAY (t_{POD})

When the supply is ramped to $V_{POR(H)}$ [2] in Figure 4, the device will require a finite time to power its internal components before the outputs are released from high impedance and can respond to an input magnetic field. Power-On Time, t_{POD} , is defined as the time it takes for the output voltage to settle within ±10% of its steady-state value under an applied magnetic field, which can be seen as the time from [1] to [A] in Figure 5. After this delay, the output will quickly approach $V_{IOUT(IP)} = \text{Sens} \times \text{IP} + V_{REF}$.

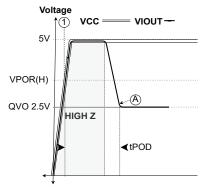
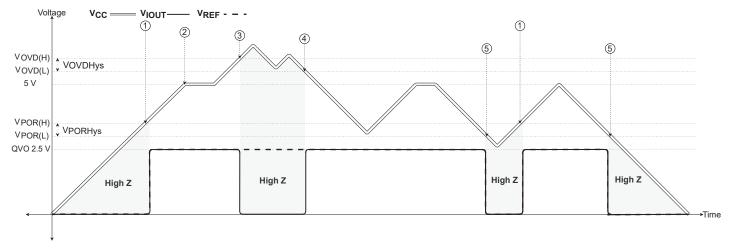


Figure 5: t_{POD}, R_L = Pull-Up







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Overvoltage Detection (OVD)

To ensure that the device output is reporting accurately, the device contains an overvoltage detection flag. This flag on V_{IOUT} can be used to alert the system that the supply voltage is outside of the operational limits. When V_{CC} raises above $V_{OVD(H)}$ [3] in Figure 6, V_{IOUT} will go high impedance and be pulled by the load resistor to V_{CC} or GND. V_{REF} continues to output normally.

There is hysteresis between OVD enable and disable thresholds to reducing nuisance flagging and clears.

The enable time for OVD, $t_{OVD(E)}$, is the time from $V_{OVD(H)}$ [4] to OVD flag [B] in Figure 6. The enable flag for OVD has a counter to reduce transients faster than 64 µs from triggering nuisance flags.

The disable time for OVD, $t_{OVD(D)}$, is the time from $V_{OVD(L)}$ [5] until the device returns to normal operation [C] in Figure 6. The OVD disable time does not have a counter.

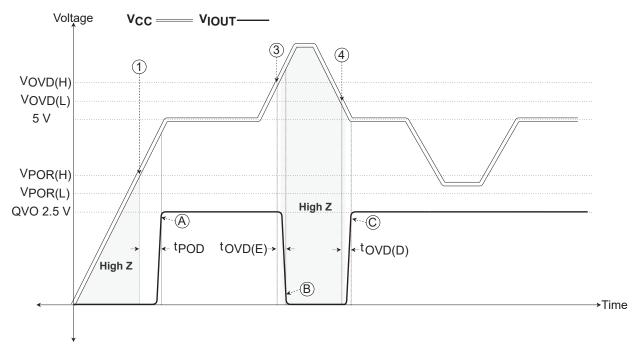


Figure 6: t_{POD} and $t_{OVD(E/D)}$ with R_L = Pull-Up



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

Absolute Maximum Ratings

These are the maximum application or environmental conditions that the device can be subjected before damage may occur.

SUPPLY ZENER CLAMP VOLTAGES

If the voltage applied to the device continues to increase past overvoltage detection, there is a point when the Zener diodes will turn on. These internal diodes are in place to protect the device from short high voltage or ESD events and should not be used as a feature to reduce the voltage on a line. Continued exposure to voltages higher than normal operating voltage, V_{CC} , can weaken or damage the Zener diodes, which will potentially damage the part.

FORWARD AND REVERSE SUPPLY VOLTAGE

These are the largest voltage magnitudes that can be supplied to V_{CC} from GND during programing or transient switching. This voltage should not be used as a DC voltage bias for an extended time.

FORWARD AND REVERSE OUTPUT VOLTAGE

The Forward Output Voltage or V_{FIOUT} voltage can be no greater than V_{CC} + 0.5 up to 6.5 V. This is the greatest voltage that the output can be biased with from GND during programming or transient switching. The Reverse Output Voltage or V_{RIOUT} should not drop below –0.5 V during programming or transient switching. These voltages should not be used as a DC voltage bias for an extended time.

FORWARD AND REVERSE REFERENCE/FAULT VOLTAGE

The Forward Reference/Fault Voltage or V_{F-RF} voltage can be no greater than V_{CC} + 0.5 up to 6.5 V. This is the greatest voltage that the V_{REF} and V_{OCF} can be biased with from GND during programming or transient switching. The Reverse Output Voltage or V_{R-RF} should not drop below –0.5 V during programming or transient switching. These voltages should not be used as a DC voltage bias for an extended time.

OUTPUT SOURCE AND SINK CURRENT

This is the maximum current that $\rm V_{\rm IOUT}$ can passively sink or source before damage may occur.

AMBIENT TEMPERATURE (T_A)

This is the ambient temperature of the device. The Operating Ambient Temperature Range is the ambient temperature range that the Common Electricals and Common Performance Characteristics limits are valid. The Optimized Ambient Temperature Range is the ambient temperature range that the device-specific performance characteristics limits are valid. ACS37002L devices have optimized performance in the -40° C to 150° C ("L" temperature) range. ACS37002K devices have optimized performance in the -40° C to 125° C ("K" temperature) range. The -40° C to 125° C ("K" temperature) range devices have Device Specific Performance optimized within the -40° C to 125° C temperature range but will still operate in the -40° C to 150° C ("L" temperature) range.



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

DEFINITIONS OF OPERATING AND PERFORMANCE CHARACTERISTICS

Zero Current Voltage Output (VIOUT(Q), QVO)

Zero Current Voltage Output or $V_{IOUT(Q)}$ (also called QVO) is defined as the voltage on the output, V_{IOUT} when zero amps are applied through I_p.

QVO Temperature Drift (V_{QE})

QVO Temperature Drift, or V_{QE} , is defined as the drift of QVO from room to hot or room to cold (25°C to 125/150°C or 25°C to -40°C respectively). To improve over temperature performance the temperature drift is compensated with Allegro factory trim to remain within the limits across temperature.

Reference Voltage (V_{REF})

There is a Voltage Reference Output, (V_{REF}) on the ACS37002. This output reports the zero current voltage for the output channel V_{IOUT} allowing for differential measurement and a device referred supply for the VOC pin.

Reference Voltage Temperature Drift (V_{RE})

Reference Voltage Temperature Drift, or V_{RE} , is defined as the drift of V_{REF} from room to hot or room to cold (25°C to 125/150°C or 25°C to -40°C respectively).

Offset Voltage (V_{OE})

Offset Voltage, or V_{OE} , is defined as the difference between QVO and V_{REF} (see Figure 7). V_{OE} includes the drift of QVO minus V_{REF} from room to hot or room to cold (25°C to 125/150°C or 25°C to -40°C respectively).

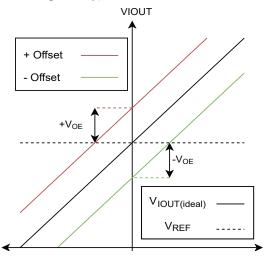


Figure 7: Offset (V_{OE}) Between V_{IOUT} and V_{REF}

Output Saturation Voltage (V_{SAT(HIGH/LOW)})

Output Saturation Voltage, or V_{SAT} , is defined as the voltage that the V_{IOUT} does not pass as a result to an increasing magnitude of current. $V_{SAT(HIGH)}$ is the highest voltage the output can drive to while, $V_{SAT(LOW)}$ is the lowest. This can be seen in Figure 8. Note that changing the sensitivity does not change the V_{SAT} points.

OUTPUT VOLTAGE OPERATING RANGE (VOOR)

The Output Voltage Operating Range, or V_{OOR} , is the functional range for linear performance of V_{IOUT} and its related datasheet parameters. This can be seen in Figure 8. The V_{OOR} is the output region that the performance accuracy parameters are valid. It is possible for the output to report beyond these voltages until V_{SAT} , but certain parameters cannot be guaranteed. The output performance is demonstrated in Figure 8 through and beyond the V_{OOR} .

Voltage Output Operating Range for V _{CC} and Output Modes, V _{OOR(Vcc, Mode)}				
$V_{CC}(V)$	Bidrectional Unidirectional			
3.3	3.3 ±1.32 +2.6			
5 ±2		+4		

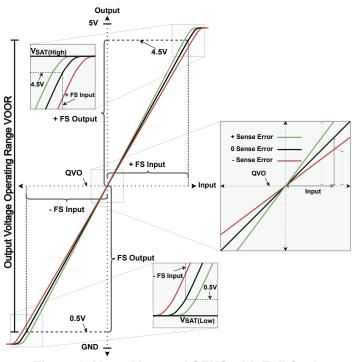


Figure 8: V_{OOR}, V_{SAT} and SENS with Full Scale



Sensitivity (Sens)

Sensitivity, or Sens, is the ratio of the output swing versus the applied current through the primary conductor, Ip. This current causes a voltage deviation away from QVO on the V_{IOUT} output until V_{SAT}. The magnitude and direction of the output voltage swing is proportional to the magnitude and direction of the applied current. This proportional relationship between output and input is Sensitivity and is defined as:

$$Sens = \frac{V_{\rm IOUT(I1)} - V_{\rm IOUT(I2)}}{I_1 - I_2}$$

where I_1 and I_2 are two different currents, and where $V_{IOUT(I1)}$ and V_{IOUT(I2)} are the voltages of the device at the applied currents. V_{IOUT}, I₁, or I₂ can be QVO with zero current.

Sensitivity Error (E_{sens})

Sensitivity Temperature Drift, or E_{sens} , is the drift of Sens from room to hot or room to cold (25°C to 125°C or 25°C to -40°C respectively). No trimming/programming is needed as temperature drift is compensated with Allegro factory trim.

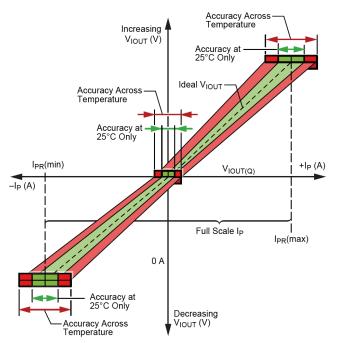


Figure 9: Output Accuracy Pocket for Room and **Across Temperature**

Gain Selection Pins

The ACS37002 features external gain selection pins that configures the device sensitivity. The gain select logic is latched based on the pin voltage at startup. Either pin may be shorted directly to VCC or GND, which is logic 1 or 0 respectively. Both pins include an internal 1 MQ pull-down resistor to GND. Externally floating pins will be interpreted as logic 0; if both pins are floating, the device will be in the 00 configuration. Specific gain select performance can be found in the selection Performance Characteristics table. To change the gain of the device, refer to Figure 18 in the Application and Theory section.

Full Scale (FS)

Full Scale, or FS, is a method to relate an input and/or output to the max input and/or output of the device. For example, 50%FS of a 10A sensor is 5A, or 50% of its maximum input current. The 50% input of 5A will cause the output to move 50%, or 50%FS. FS is used to interchangeably refer to input and output deviations when discussing input steps, fault trip thresholds and relating input to output performance. FS_{INPUT} is the input bias that results in FS_{OUTPUT} and these two are directly related by the device actual sensitivity. Both FS input and output can be seen in Figure 8, labeled as positive or negative FS input and FS output. The equation for input referred FS for a 5V bidirectional device is:

$$FS = \frac{V_{OOR(5V,Bi)}}{Sens_{Actual}} = \pm \frac{2V}{Sens_{Actual}}$$

Note: that a percentage change in FS_{INPUT} is equivalent to a resultant percentage change of FS_{OUTPUT} and visa versa.

Nonlinearity (ELIN)

As the amount of field applied to the part changes, the sensitivity of the device can also change slightly. This is referred to as linearity error or E_{LIN} (see Figure 10). Consider two currents, $I_1(1/2 \text{ FS})$ and $I_2(\text{FS})$. Ideally, the sensitivity of the device is the same for both fields. Linearity Error is calculated as the percent change in sensitivity from one field to another. Error is calculated separately for positive $(E_{LIN(+)})$ and negative $(E_{LIN(-)})$ currents, and the percent errors are defined as:

$$E_{LIN(\pm)} = \left(1 - \frac{Sense_{I2\pm}}{Sens_{I1\pm}}\right) \times 100\%$$

S

where:

$$Sens_{IX+} = \frac{V_{IOUT(IX+)} - V_{REF}}{I_{X+}}$$
$$Sens_{IX-} = \frac{V_{IOUT(IX-)} - V_{REF}}{I_{X-}}$$



Ix are positive and negative currents through I_{P} , such that $|I_{+2}| = 2 \times |I_{+1}|$ and $|I_{-2}| = 2 \times |I_{-1}|$. $E_{LIN} = max(E_{LIN(+)}, E_{LIN(-)})$

Total Output Error (E_{TOT})

The Total Output Error is the current measurement error from the sensor IC as a percentage of the actual applied current. This is equivalent to the difference between the ideal output voltage and the actual output voltage, divided by the ideal sensitivity, relative to the current applied to the device, or simplified to:

$$E_{TOT} = \frac{V_{IOUT(ACTUAL)} - (Sens_{(IDEAL)} \times I_{PR} + V_{REF})}{(Sens_{(IDEAL)} \times I_{PR})} \times 100$$

Total Output Error incorporates all sources of error and is a function of current. At relatively high currents, Total Output Error will be mostly due to sensitivity error, and at relatively low inputs, Total Output Error will be mostly due to Offset Voltage (V_{OE}). At I = 0 A, Total Output Error approaches infinity due to the offset. An example of total error at FS can be seen in Figure 10.

Note: Total Output Error goes to infinity as the amount of applied field approaches 0 A.

Power Supply Offset Error (V_{PS})

Power Supply Offset Error or $V_{OE(PS)}$ is defined at the offset error in mV between V_{CC} and $V_{CC}\pm10\%$ V_{CC} . For a 5 V device, this is 5 to 4.5 V and 5 to 5.5 V. For a 3.3 V device, this is 3.3 to 3 V and 3.3 to 3.6 V.

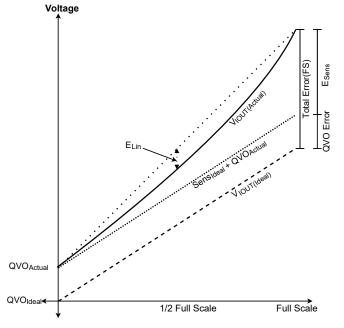


Figure 10: Accuracy Error

Offset Power Supply Rejection Ratio (PSRR₀)

The Offset Power Supply Rejection Ratio or PSRR_O is defined as 20 × log of the ratio of the change of QVO in volts over a $\pm 100 \text{ mV}$ variable AC V_{CC} centered at 5 V reported as dB in a specified frequency range. This is an AC version of the V_{OE(PS)} parameter. The equation is shown below:

$$PSRR_{O} = 20 \times \log\left(\frac{\Delta QVO}{\Delta V_{CC}}\right)$$

Power Supply Sensitivity Error (E_{PS})

Power Supply Sensitivity Error, or $E_{Sens(PS)}$, is defined as the percent sensitivity error measured between V_{CC} and $V_{CC}\pm10\%$. For a 5 V device, this is 5 to 4.5 V and 5 to 5.5 V. For a 3.3 V device, this is 3.3 to 3 V and 3.3 to 3.6 V.

Sensitivity Power Supply Rejection Ratio (PSRR_S)

The Sensitivity Power Supply Rejection Ratio or PSRR_S is defined as 20 × log of the ratio of the % change the sensitivity over the % change in V_{CC} (±100 mV variable AC V_{CC} centered at 5 V) reported as dB in a specified frequency range. This is the AC version of the E_{Sens(PS)} parameter. The equation is shown below:

$$PSRR_{S} = 20 \times \log\left(\frac{\Delta\%Sens}{\Delta V_{CC}}\right)$$



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

FAULT BEHAVIOR

Overcurrent Fault (OCF)

As the output swings, the Overcurrent Fault pin will trigger with an active low flag if the sensed current exceeds its comparator threshold. This is internally compared with either the factoryprogrammed thresholds or via the VOC voltage when $V_{VOC} >$ 0.1 V. This flag trips symmetrically for the positive and negative OCF operating point.

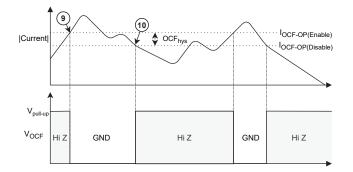
The implementation for the OCF circuitry is accurate over temperature and does not require further temperature compensation as it is dependent on the Sens and V_{OFF} parameters that are factory-trimmed flat over temperature.

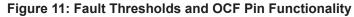
OVERCURRENT FAULT OPERATING RANGE/POINT (I_{OCF-OR}, I_{OCF-OP})

Overcurrent Fault Operating Range is the functional range that the OCF thresholds can be set in terms of percentage of full-scale output swing. The Overcurrent Fault Operating Point is the specific point at which the OCF trigger will occur, and is set by either V_{VOC} or the factory default setting. The I_{OCF-OP} can be seen in Figure 11 as [9] along with the FAULT pin functionality.

OVERCURRENT FAULT HYSTERESIS (IOCF-HYST)

Overcurrent Fault Hysteresis or $I_{OCF-HYST}$ is defined as the magnitude of percent FS that must drop before a fault assertion will be cleared. This can be seen as the separation between the voltages [9] to [10] in Figure 11. Note the MASK and HOLD functionality are independent of each other. The ACS37002 comes standard with an OCF_{HYS} of 120 mV (on the output) or 6%FS for a 5 V device and 9%FS for a 3.3 V device.





VOLTAGE OVERCURRENT PIN (VOC)

The fault trip points can be set using the VOC pin as the direct analog input for the fault trip point. The VOC pin voltage can be set using resistor dividers from V_{REF} on bidirectional devices. The fault performance is valid when V_{VOC} is within the VOC Operating Voltage Range or <0.1 V. The device will respond to voltage outside of the defined valid performance region with varied results. For a 5 V bidirectional device, setting the VOC pin to 0.5 V selects the minimum trip point, $I_{FAULT(min)}$, and setting the pin to 2 V selects the maximum trip point, $I_{FAULT(max)}$ as defined by selection performance tables. All voltages between 0.5 to 2 V for 5 V option and 0.33 to 1.321 V for 3.3 V option can linearly select a trip point between the minimum and maximum levels, as shown in Figure 12. When $V_{OC} < 0.1$ V, the internal EEPROM fault level will be used.

The resulting equation for the fault is:

$$OCF_{\text{\%FS}} [\%] = \frac{V_{\text{OC(V_{CC})}} [V]}{V_{\text{OC(V_{CC})100\%}} [V]} \times 100 [\%]$$
$$I_{OCT} [A] = OCF_{\text{\%FS}} [\%] \times I_{DD} [A]$$

Table 1: V_{OC(Vcc)} thresholds and corresponding percentage of the Full-Scale Output for Bidirectional and Unidirectional operational modes

N 00	V 00	Fault Operation Point %FS		
V _{OC(3.3V)} (V)	V _{OC(5V)} (V)	Bidirectional	Unidirectional	
<().1	100% (factory default)	50% (factory default)	
0.330	0.5	50%	25%	
0.466	0.75	75%	37.5%	
0.661	1	100%	50%	
0.826	1.25	125%	62.5%	
0.991	1.5	150%	75%	
1.156	1.75	175%	85%	
1.321	2	200%	100%	

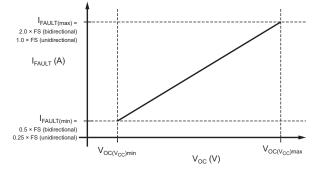


Figure 12: VOC Functional Range



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

OVERCURRENT FAULT ERROR (EOCE)

Fault Error or E_{OCF} is the error between the I_{OCF-OP(actual)} and IOCF-OP(ideal).

OVERCURRENT FAULT RESPONSE TIME (toce)

Overcurrent Response Time or t_{OCF} is defined as the time from the input reaches the operating point [9] (seen in Figure 13) until the OCF pin falls below V_{FAULT-ON} [G]. If the OCF Mask is disabled, then t_{OCF} is equal to t_{OCF-R} seen as the time from [9] until [F].

OVERCURRENT FAULT REACTION TIME (toce-R)

Overcurrent Reaction Time or t_{OCF-R} is defined as the time from the current input rising above I_{OCF-OP} at point [9] in Figure 13 until the OCF pin reaches V_{OCF-ON} at point [F] with the OCF mask disable. This is the time required for the device to recognize and clear the fault, seen as the time between [10] until [I].

OVERCURRENT FAULT MASK TIME (tocf-mask)

Overcurrent Fault Mask Time or t_{OCF-MASK} is defined as the additional amount of time the OCF must be present beyond the t_{OCF-R} time (seen in Figure 13 [F] until [G]). This is to reduce nuisance tripping of the FAULT pin. If an OCF occurs, but does not persist beyond t_{OCF-R} + t_{OCF-MASK}, it is not reported by the device (seen in Figure 14). This prevents short transient spikes from causing erroneous OCF flagging. Factory default setting is $t_{OCF-MASK} = 0 \ \mu s.$

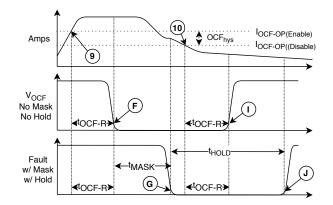


Figure 13: General Fault Timing. Note: the MASK and HOLD functionality are independent of each other

OVERCURRENT FAULT HOLD TIME (tocf-hold)

Overcurrent Fault Hold Time or t_{OCF-HOLD} is defined as the minimum time OCF flag will be asserted after a sufficient OCF event. After the hold time has been reached, the OCF will release if the OCF condition has ended (seen in Figure 13 [G] until [J]) or persist if the OCF condition is still present (seen in Figure 15 [G] until [J]). Factory default is 0 ms.

OVERCURRENT FAULT PERSIST

The ACS37002 has a fault persist option that will maintain the OCF flag if a flag occurred until a POR event.

OCF DISABLE

The ACS37002 has the ability to disable overcurrent fault functionality; when this is disabled, the OCF pin will remain in high Z.

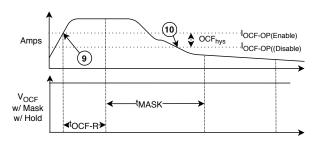


Figure 14: Fault Condition Clearing Before Mask Time Is Reached

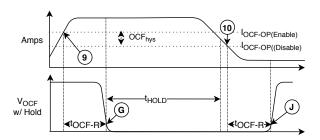


Figure 15: Fault Hold with Clear Fault After Hold Time



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

RESPONSE CHARACTERISTICS DEFINITIONS AND PERFORMANCE DATA

Response Time (t_{RESPONSE})

The time interval between a) when the sensed input current reaches 90% of its final value, and b) when the sensor output reaches 90% of its full-scale value.

Propagation Delay (t_{pd})

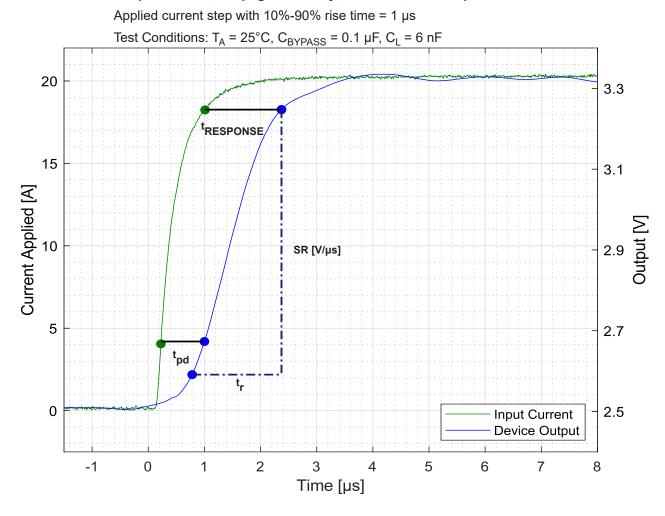
The time interval between a) when the sensed input current reaches 20% of its full-scale value, and b) when the sensor output reaches 20% of its full-scale value.

Rise Time (t_r)

The time interval between a) when the sensor reaches 10% of its full-scale value, and b) when it reaches 90% of its full-scale value.

Output Slew Rate (SR)

The rate of change $[V/\mu s]$ in the output voltage from a) when the sensor reaches 10% of its full-scale value, and b) when it reaches 90% of its full-scale value.



Response Time, Propagation Delay, Rise Time, and Output Slew Rate



Temperature Compensation

To help compensate for the effects temperature has on performance, the ACS37002 has an integrated internal temperature sensor. This sensor and compensation algorithms help to standardize device performance over the full range of optimized temperatures. This allows for room temperature system calibration and validation of end-of-line modules.

Temperature Compensation Update Rate

There is an 8 ms update time that is required to maintain a valid temperature compensated output; that is, temperature compensations are calculated and applied every 8 ms.



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

APPLICATION AND THEORY

Application Circuits

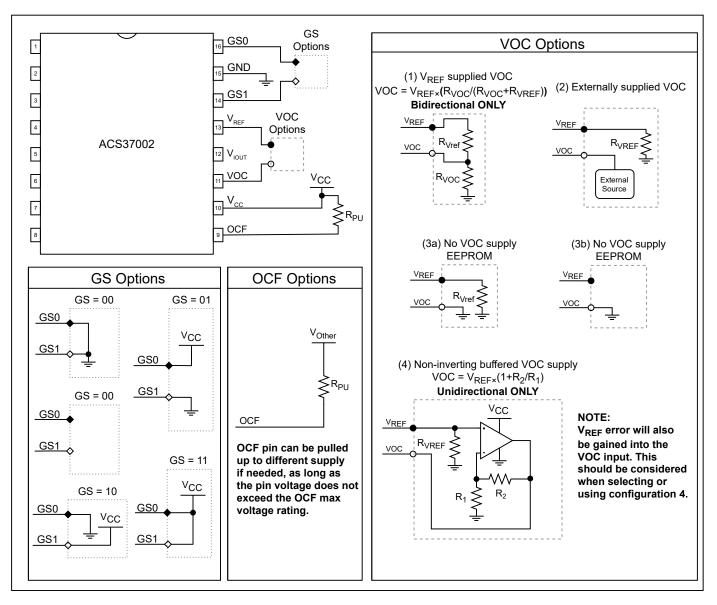


Figure 16: Applications Circuits for GAIN_SEL, VOC, and FAULT pin

These configurations are simplified to the network required for functionality. Bypass and load capacitors are recommend for best performance.



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

Theory and Functionality – VOC and OCF

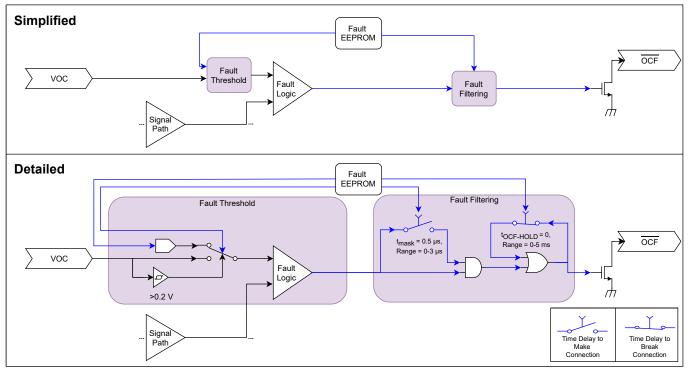


Figure 17: OCF Signal Path Simplified and Detailed Blocks of Functionality

VOC DRIVEN BY NON-INVERTING BUFFERED VREF

If the VOC pin is being driven by a non-inverted buffered V_{REF} , it is important to consider that any error from the V_{REF} pin will be gained as well. For instance, if V_{REF} error is +10 mV and the gain = 4 for the non-inverting operational amplifier, then the VOC pin will be 40 mV from the expected target. For unidirectional devices, OCF would be subjected to an additional 4% error due to the error propagation from V_{REF} through the gain stage.

POWER SUPPLY DECOUPLING CAPACITOR AND OUTPUT CAPACITIVE LOADS

The higher the capacitive load on the outputs (V_{REF} , V_{IOUT}), the larger the decoupling capacitor should be on the power supply (V_{CC}) to maintain performance.

C _{LOAD}	C _{BYPASS}
0 nF	>100 nF
1 nF	>100 nF
3 nF	>1 µF
6 nF	>10 µF



Dynamically Change Gain in a System

The ACS37002 has GAIN_SEL pins that are used to change the gain of the device on startup. If a more dynamic gain is desired, then reduce V_{CC} below $V_{POR(L)}$ and restart the device by returning V_{CC} to the nominal voltage with the new desired GAIN_SEL configuration. The GAIN_SEL pin voltage must greater than the

desired configuration voltage ($V_{H(SEL)}$ or $V_{L(SEL)}$) at or before $V_{CC} > V_{POR(H)}$ in order to successfully change the device gain. The GAIN_SEL pin voltage is latched at startup, and any changes to the pin voltages after the devices V_{IOUT} comes out of high Z will not affect gain. The cycle time to complete this operation is up to $2 \times t_{POD}$.

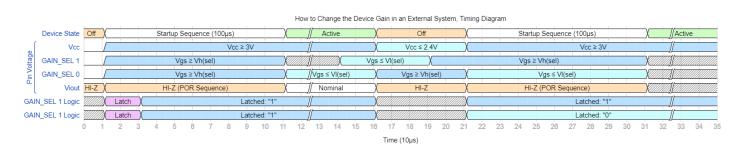


Figure 18: GAIN_SEL Dynamic Gain Changing Timing Diagram



400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

THERMAL PERFORMANCE

Thermal Rise vs. Primary Current

Self-heating due to the flow of current should be considered during the design of any current sensing system. The sensor, printed circuit board (PCB), and contacts to the PCB will generate heat as current moves through the system.

The thermal response is highly dependent on PCB layout, copper thickness, cooling techniques, and the profile of the injected current. The current profile includes peak current, current "on-time", and duty cycle. While the data presented in this section was collected with direct current (DC), these numbers may be used to approximate thermal response for both AC signals and current pulses.

The plot in Figure 19 shows the measured rise in steady-state die temperature of the ACS37002 versus continuous current at an ambient temperature, T_A , of 25 °C. The thermal offset curves may be directly applied to other values of T_A . Conversely, Figure 20 shows the maximum continuous current at a given T_A . Surges beyond the maximum current listed in Figure 21 are allowed given the maximum junction temperature, $T_{J(MAX)}$ (165°C), is not exceeded.

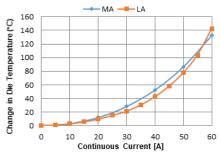


Figure 19: Self heating in the MA and LA package due to current flow

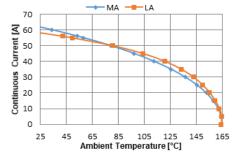


Figure 20: Maximum Continuous Current at a Given T_A

The thermal capacity of the ACS37002 should be verified by the end user and is specific to the application. The maximum junction temperature, $T_{J(MAX)}$ (165°C), should not be exceeded. Further information on this application testing is available in the DC and Transient Current Capability application note on the Allegro website (http://www.allegromicro.com/en/Design-Center/ Technical-Documents/Hall-Effect-Sensor-IC-Publications/DCand-Transient-Current-Capability-Fuse-Characteristics.aspx).

Evaluation Board Layout

Thermal data shown in Figure 19 and Figure 20 was collected using the ASEK37002 Evaluation Board (TED-0002825). This board includes 750 mm² of 4 oz. copper (0.1388 mm) connected to pins 1 through 4, and to pins 5 through 8, with thermal vias connecting the layers. Top and bottom layers of the PCB are shown below in Figure 21.

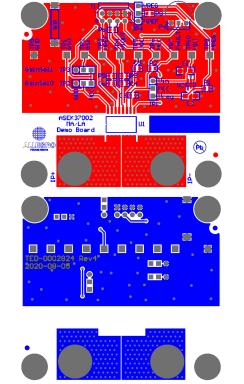


Figure 21: Top and Bottom Layers for ASEK37002 Evaluation Board

Gerber files for the ASEK37002 evaluation board are available for download from the Allegro website. See the technical documents section of the ACS37002 webpage (https://www.allegromicro.com/en/products/sense/current-sensor-ics/zero-to-fifty-ampintegrated-conductor-sensor-ics/acs37002).



400 kHz, High Accuracy Current Sensor with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

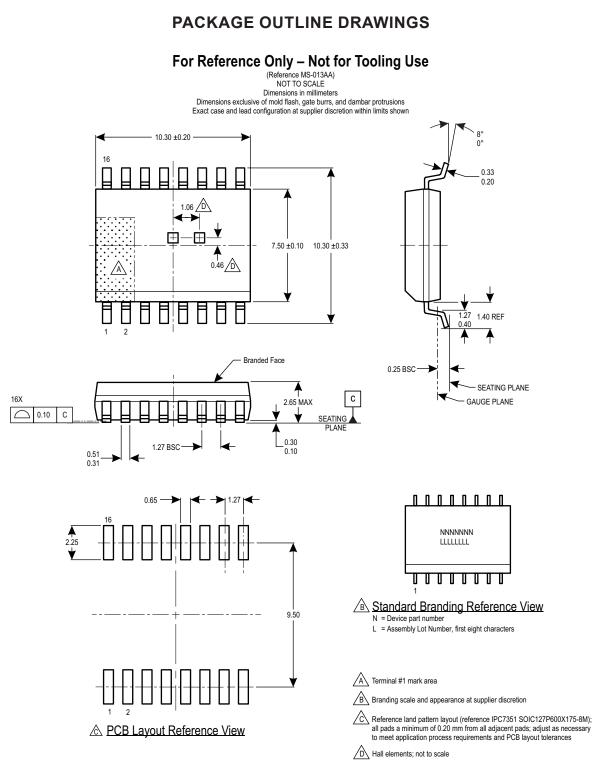
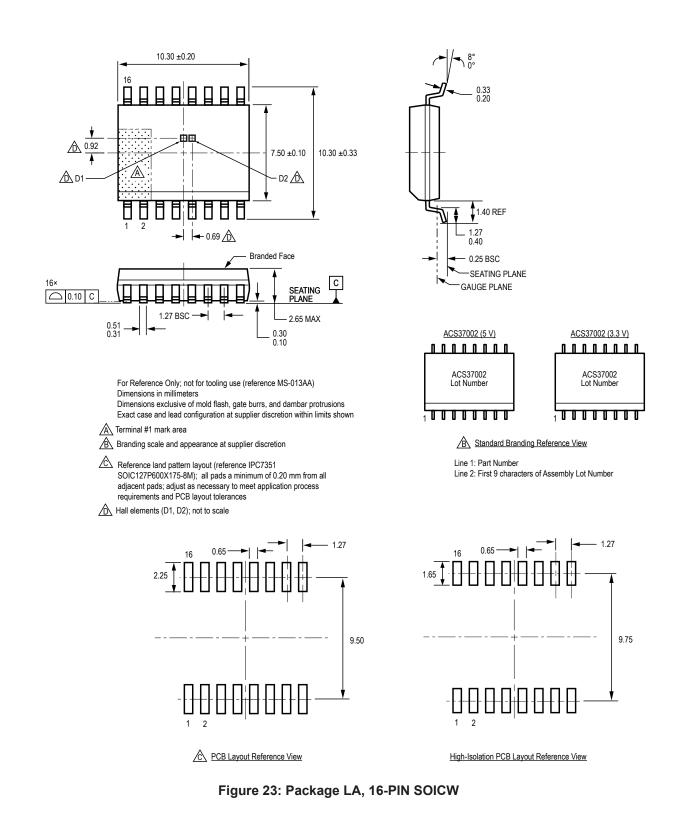


Figure 22: Package MA, 16-Pin SOICW



400 kHz, High Accuracy Current Sensor with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package





400 kHz, High Accuracy Current Sensor

with Pin-Selectable Gains and Adjustable Overcurrent Fast Fault in SOICW-16 Package

Revision History

Number	Date	Description
-	June 24, 2020	Initial release
1	July 8, 2020	Updated Features and Benefits, Selection Guide (page 2), Working Voltage values (page 4), Footnote 2 (pages 10-19), Voltage Overcurrent Pin section (page 30), and Branding (page 38)
2	October 16, 2020	Updated Features and Benefits, Description, and Figure 1 (page 1); added UL certification (page 2); updated Selection Guide table (page 2), Forward Output Voltage and Reverse Output Voltage symbols (page 3), Isolation Characteristics and MA Package Specific Performance tables (page 4), Supply Voltage, Supply Bypass Capacitor, Primary Conductor Resistance, Power-On Reset Voltage, Power-On Time, Undervoltage and Undervoltage Detection Threshold (page 7), Rise Time, Response Time, Propagation Delay Time, Noise Density (page 8), VOC Operating Voltage Range, OCF Reaction Time, OCF Mask, OCF Response Time (page 9); added footnote 4 (page 9); Performance Characteristic tables (pages 10-19); updated Current Sensing Range and Sensitivity values (pages 21-23); added Functional Description (pages 24-27), Definitions of Operating and Performance Characteristics (pages 28-32); updated Figure 20 (page 34),Theory and Functionality (pages 35-36).
3	December 16, 2020	Updated UVD and OVD Threshold test conditions (page 7); removed Overshoot and Settling Time sections and Figure 19 (page 33); fixed Figure 18 (page 33) graphical issue; updated Figure 19 (page 34), and other minor editorial updates.
4	May 14, 2021	Updated Features and Benefits, Description, Figure 1 caption (pages 1-2), Table of Contents (page 3); added Maximum Continuous Current (page 4), MSL Rating (page 5); updated Dielectric Strength Test Voltage (page 5), Reference Resistive Load, Primary Conductor Inductance, Typical Buffer Resistance (page 8), Internal Bandwidth, Rise Time, Response Time, Propagation Delay, Noise Density, Noise, Power Supply Rejection Ratio Offset, and Power Supply Rejection Ratio Sens test conditions (page 9), OCF Response Time test conditions and footnote 2 (page 10), Zero Current Output Voltage (page 23), Current Sensing Range, Overcurrent Fault Operating Range, and Zero Current Output Voltage (page 24), Functional Description Diagrams (pages 25-29), Definition of Operating and Performance Characteristics diagrams and equations (pages 30-32), Fault Behavior Diagrams (page 34), Response Characteristics Definitions and Performance Data section (pages 35-36), Application and Theory diagram (page 38), Thermal Performance diagram (page 40), and other minor editorial updates.
5	June 24, 2021	UVD functionality disabled (all pages); updated part numbers (pages 2, 11-14, 19); updated Isolation and Package Characteristics tables (page 5)
6	September 14, 2021	Updated part numbering schematic (page 2) and other minor editorial updates (pages 2, 4, 9, 38)
7	November 10, 2021	Removed footnote 4 (page 2); updated Power Supply Offset Error (page 9, Total Error and Total Error Components and Total Error and Total Error Components Including Lifetime Drifts values and footnotes (pages 21-24); updated Total Output Error equation (page 30), and package drawing (page 40).

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